NSN 5961-01-282-9860

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.140 inches and 0.185 inches
Terminal Length:
Between 1.000 inches and 1.300 inches
Overall Diameter:
Between 0.085 inches and 0.140 inches
Function For Which Designed:
Transient suppressor
Mounting Method:
Terminal
Features Provided:
Quality assurance level tx
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
95.0 breakdown voltage, instantaneous and 105.0 breakdown voltage, instantaneous and 76.0 working peak reverse voltage
Current Rating Per Characteristic:
1.00 microamperes forward current, average peak and 12.00 milliamperes collector current, dc torr
Power Rating Per Characteristic:
2.0 watts small-signal input power, common-collector major
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/516 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0